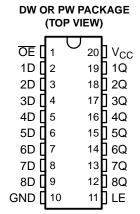
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### **FEATURES**

- Controlled Baseline
  - One Assembly/Test Site, One Fabrication Site
- Extended Temperature Performance of –40°C to 125°C
- Enhanced Diminishing Manufacturing Sources (DMS) Support
- Enhanced Product-Change Notification
- Qualification Pedigree (1)
- Operates From 2 V to 3.6 V
- Inputs Accept Voltages to 5.5 V
- Max t<sub>nd</sub> of 6.9 ns at 3.3 V
- Typical V<sub>OLP</sub> (Output Ground Bounce) <0.8 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot) >2 V at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C
- (1) Component qualification in accordance with JEDEC and industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

- Supports Mixed-Mode Signal Operation on All Ports (5-V Input/Output Voltage With 3.3-V V<sub>CC</sub>)
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation



# **DESCRIPTION/ORDERING INFORMATION**

The SN74LVC573A-EP octal transparent D-type latch is designed for 2.7-V to 3.6-V  $V_{CC}$  operation.

This device features 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. It is particularly suitable for implementing buffer registers, input/output (I/O) ports, bidirectional bus drivers, and working registers.

While the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the logic levels at the D inputs.

### ORDERING INFORMATION

T <sub>A</sub>	PACKA	GE <sup>(1)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 125°C	SOIC - DW	Reel of 2000	SN74LVC573AQDWREP	C573AEP
-40 C to 125 C	TSSOP – PW	Reel of 2000	SN74LVC573AQPWREP	C573AEP

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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# **DESCRIPTION/ORDERING INFORMATION (CONTINUED)**

A buffered output-enable  $(\overline{OE})$  input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

OE does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

This device is fully specified for partial-power-down applications using  $I_{off}$ . The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

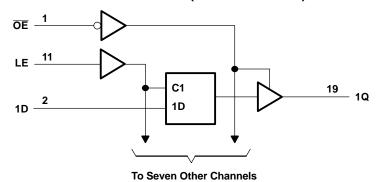
To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Inputs can be driven from either 3.3-V or 5-V devices. This feature allows the use of this device as a translator in a mixed 3.3-V/5-V system environment.

# FUNCTION TABLE (EACH LATCH)

	INPUTS		OUTPUT
ŌĒ	LE	D	Q
L	Н	Н	Н
L	Н	L	L
L	L	X	$Q_0$
Н	X	X	Z

# **LOGIC DIAGRAM (POSITIVE LOGIC)**





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# Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	6.5	V
$V_{I}$	Input voltage range (2)		-0.5	6.5	V
Vo	Voltage range applied to any output in the high-impedance	or power-off state(2)	-0.5	6.5	V
Vo	Voltage range applied to any output in the high or low state	(2)(3)	-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
Io	Continuous output current	<u> </u>		±50	mA
	Continuous current through V <sub>CC</sub> or GND			±100	mA
0	Declare thermal impedance (4)	DW package		58	°C/W
$\theta_{JA}$	Package thermal impedance (4)	PW package		83	-C/VV
T <sub>stg</sub>	Storage temperature range <sup>(5)</sup>		-65	150	°C

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- 3) The value of V<sub>CC</sub> is provided in the recommended operating conditions table.
- (4) The package thermal impedance is calculated in accordance with JESD 51-7.
- (5) Long-term high-temperature storage and/or extended use at maximum recommended operating conditions may result in a reduction of overall device life. See http://www.ti.com/ep\_quality for additional information on enhanced plastic packaging.

# Recommended Operating Conditions<sup>(1)</sup>

			MIN	MAX	UNIT
V	Cumply veltore	Operating		3.6	V
V <sub>CC</sub>	Supply voltage	Data retention only	1.5		V
$V_{IH}$	High-level input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		V
$V_{IL}$	Low-level input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		8.0	V
$V_{I}$	Input voltage		0	5.5	V
V	Output valtage	High or low state	0	$V_{CC}$	V
Vo	Output voltage	3-state	0	5.5	V
	High level output ourrent	V <sub>CC</sub> = 2.7 V		-12	A
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 3 V		-24	mA
	Law lavel autout august	V <sub>CC</sub> = 2.7 V		12	A
I <sub>OL</sub>	Low-level output current $V_{CC} = 3 \text{ V}$			24	mA
Δt/Δν	Input transition rise or fall rate			6	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	125	°C

<sup>(1)</sup> All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

# SN74LVC573A-EP **OCTAL TRANSPARENT D-TYPE LATCH** WITH 3-STATE OUTPUTS

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## **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		V <sub>cc</sub>	MIN TYP		UNIT
	$I_{OH} = -100 \mu A$		2.7 V to 3.6 V	V <sub>CC</sub> - 0.2		
V	1 - 12 mA		2.7 V	2.2		V
V <sub>OH</sub>	I <sub>OH</sub> = −12 mA		3 V	2.4		V
	$I_{OH} = -24 \text{ mA}$	3 V	2.2			
	I <sub>OL</sub> = 100 μA		2.7 V to 3.6 V		0.2	
$V_{OL}$	I <sub>OL</sub> = 12 mA		2.7 V		0.4	V
	I <sub>OL</sub> = 24 mA		3 V		0.55	
I <sub>I</sub>	V <sub>I</sub> = 0 to 5.5 V		3.6 V		±5	μΑ
l <sub>OZ</sub>	V <sub>O</sub> = 0 to 5.5 V		3.6 V		±15	μΑ
	$V_I = V_{CC}$ or GND	1 - 0	3.6 V		10	^
lcc	$3.6 \text{ V} \le \text{V}_{\text{I}} \le 5.5 \text{ V}^{(2)}$	$I_O = 0$	3.0 V		10	μΑ
$\Delta I_{CC}$	One input at $V_{CC}$ – 0.6 V, Other inputs at $V_{CC}$ or GND		2.7 V to 3.6 V		500	μΑ
C <sub>i</sub>	$V_I = V_{CC}$ or GND		3.3 V	4		pF
Co	$V_O = V_{CC}$ or GND		3.3 V	5.5	,	pF

<sup>(1)</sup> All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C. (2) This applies in the disabled state only.

# **Timing Requirements**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

		V <sub>CC</sub> = 2.7 V MIN MAX		V <sub>CC</sub> = 3 ± 0.3	UNIT	
				MIN	MAX	
t <sub>w</sub>	Pulse duration, LE high	3.3		3.3		ns
t <sub>su</sub>	Setup time, data before LE↓	2		2		ns
t <sub>h</sub>	Hold time, data after LE↓	2.5		2.5		ns

# **Switching Characteristics**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	PARAMETER FROM TO (OUTPUT)		V <sub>CC</sub> = 2.7 V		$V_{CC} = 2.7 \text{ V}$ $V_{CC} = 3.3 \text{ V}$ $\pm 0.3 \text{ V}$		V <sub>CC</sub> = 3.3 V ± 0.3 V		UNIT
	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX			
	D	0		7.7	1	6.9	20		
t <sub>pd</sub>	LE	Q		8.4	1	7.7	ns		
t <sub>en</sub>	ŌĒ	Q		8.5	1	7.5	ns		
t <sub>dis</sub>	ŌĒ	Q		7	0.5	6.7	ns		

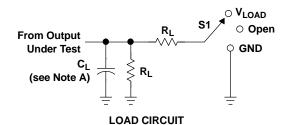
# **Operating Characteristics**

 $T_A = 25^{\circ}C$ 

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub> = 2.5 V TYP	V <sub>CC</sub> = 3.3 V	UNIT	
O Down the institution of the second state of		Outputs enabled	f 10 MHz	56	37	pF
C <sub>pd</sub>	Power dissipation capacitance per latch	Outputs disabled	f = 10 MHz	3	4	рг

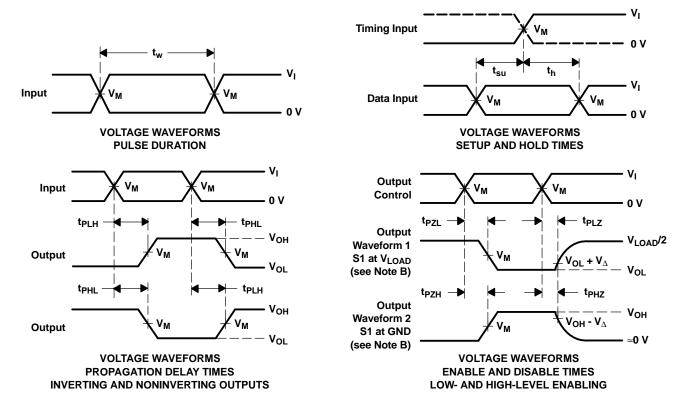


# PARAMETER MEASUREMENT INFORMATION



TEST	S1
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub> t <sub>PHZ</sub> /t <sub>PZH</sub>	V <sub>LOAD</sub> GND

.,	INPUTS		.,	.,		_	.,
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	V <sub>LOAD</sub>	CL	R <sub>L</sub>	$V_{\Delta}$
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	500 Ω	0.3 V
3.3 V $\pm$ 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	<b>500</b> Ω	0.3 V



- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O$  = 50  $\Omega$ .
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.
  - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





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### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
SN74LVC573AQDWREP	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74LVC573AQPWREP	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
V62/04667-01XE	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
V62/04667-01YE	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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### OTHER QUALIFIED VERSIONS OF SN74LVC573A-EP:

Catalog: SN74LVC573A
Automotive: SN74LVC573A-Q1
Military: SN54LVC573A

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military QML certified for Military and Defense Applications



# TAPE AND REEL INFORMATION



# TAPE DIMENSIONS + K0 - P1 - B0 W Cavity - A0 -

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



## \*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC573AQDWREP	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
SN74LVC573AQPWREP	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1





\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC573AQDWREP	SOIC	DW	20	2000	346.0	346.0	41.0
SN74LVC573AQPWREP	TSSOP	PW	20	2000	346.0	346.0	33.0

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